MSCDC450A170AG

Datasheet

SiC Diode Phase Leg Power Module

December 2019





Contents

1.1 Revision 1.0. 1 2 Product Overview. 2 Features. 2 Benefits. 3 Applications. 3 3 Electrical Specifications. 4 Absolute Maximum Ratings. 4 Electrical Performance. 4 Typical Performance Curves. 6 4 Package Specifications. 7	1 Revision History	
Features. 2 Benefits. 3 Applications. 3 3 Electrical Specifications. 4 Absolute Maximum Ratings. 4 Electrical Performance. 4 Typical Performance Curves. 6 4 Package Specifications. 7		
Features. 2 Benefits. 3 Applications. 3 3 Electrical Specifications. 4 Absolute Maximum Ratings. 4 Electrical Performance. 4 Typical Performance Curves. 6 4 Package Specifications. 7	2 Product Quantion	2
Benefits		
Applications		
Applications	Benefits	3
Absolute Maximum Ratings	Applications	3
Absolute Maximum Ratings	3 Electrical Specifications	4
Electrical Performance	Absolute Maximum Ratings	4
4 Package Specifications	Electrical Performance	4
4 Package Specifications	Typical Performance Curves	6
Package Outline Drawing	4 Package Specifications	
	Package Outline Drawing	7



1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

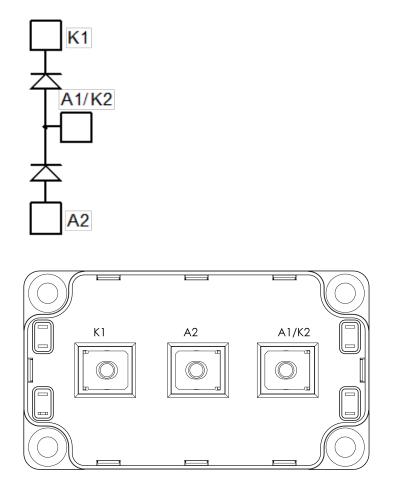
1.1 Revision 1.0

Revision 1.0 was published in December 2019. It is the first publication of this document.



2 Product Overview

This section provides the product overview for the MSCDC450A170AG device.



All ratings at Tj = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.

2.1 Features

The following are key features of the MSCDC450A170AG device:

- Silicon Carbide (SiC) Schottky diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on VF
- Low stray inductance
- M5 power connectors
- High level of integration



• Aluminum nitride (AIN) substrate for improved thermal performance

2.2 Benefits

The following are benefits of the MSCDC450A170AG device:

- Outstanding performance at high frequency operation
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

2.3 Applications

The MSCDC450A170AG device is designed for the following applications:

- Uninterruptible power supply (UPS)
- Induction heating
- Welding equipment
- High-speed rectifiers



3 Electrical Specifications

This section provides the electrical specifications for the MSCDC450A170AG device.

3.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings per diode for the MSCDC450A170AG device.

Table 1 • Absolute Maximum Ratings

Symbol	Parameter	Max Ratings	Unit	
V _{RRM}	Repetitive peak reverse voltage	1700	V	
I _F	DC forward current	T _C = 125 °C	450	A

The following table shows the Thermal and Package Characteristics of the MSCDC450A170AG device. **Table 2 • Thermal and Package Characteristics**

Symbol	Characteristic	Characteristic		Min	Max	Unit	
V _{ISOL}	RMS isolation vo 50 Hz/60 Hz	1S isolation voltage, any terminal to case t =1 minute, Hz/60 Hz				V	
Тј	Operating junct	tion temperature rai	-40	175	°C		
T _{JOP}	Recommended conditions	junction temperature under switching		-40	T _{Jmax} –25		
T _{STG}	Storage temper	rature range		-40	125		
T _C	Operating case	temperature	-40	125			
Torque	Mounting torque	To heatsink	M6	3	5	N.m	
	lorque	For terminals	M5	2	3.5	_	
Wt	Package weight				300	g	

3.2 Electrical Performance

The following table shows the electrical characteristics per diode of the MSCDC450A170AG.

Table 3 • Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _F	Diode forward voltage	I _F = 450 A	T _j = 25 °C		1.5	1.8	v
			T _j = 175 °C		2		
I _{RM}	Reverse leakage current	V _R = 1700 V	T _j = 25 °C		0.45	1.8	mA



Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
			T _j = 175 °C		2.25		
Q _C	Total capacitive charge	V _R = 900 V	V _R = 900 V		3.69		μC
С	Total capacitance	f = 1 MHz, V _R = 6	f = 1 MHz, V _R = 600 V		2.7		nF
		f = 1 MHz, V _R = 900 V			2.25		
R _{thJC}	Junction-to-case thermal resistance					0.043	°C/W



3.3 Typical Performance Curves

This section shows the typical performance curves for the MSCDC450A170AG device.

Figure 1 • Maximum Transient Thermal Impedance

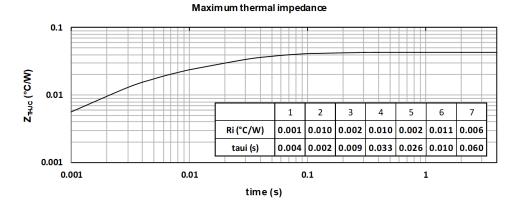


Figure 2 • Forward Current vs. Forward Voltage

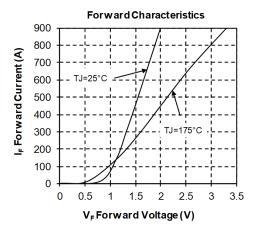
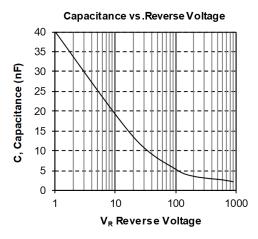


Figure 3 • Capacitance vs. Reverse Voltage





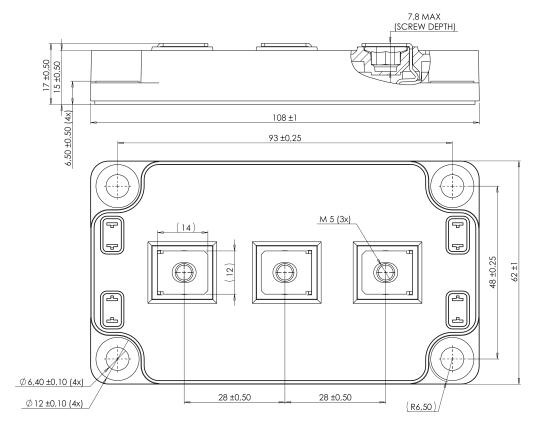
4 Package Specifications

This section shows the package specifications for the MSCDC450A170AG device.

4.1 Package Outline Drawing

The following image illustrates the package outline of MSCDC450A170AG device. The dimensions in the following figure are in millimeters.

Figure 4 • Package Outline Drawing







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